

BD375/377/379

Medium Power Linear and Switching Applications

Complement to BD376, BD378 and BD380 respectively



NPN Epitaxial Silicon Transistor

1. Emitter 2.Collector 3.Base

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage : BD375	50	V
	: BD377	75	V
	: BD379	100	V
V _{CEO}	Collector-Emitter Voltage : BD375	45	V
	: BD377	60	V
	: BD379	80	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current (DC)	2	Α
I _{CP}	*Collector Current (Pulse)	3	Α
I _B	Base Current	1	Α
P _C	Collector Dissipation (T _C =25°C)	25	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	744	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	WWW.DE	Voltage BD375 BD377 BD379	I _C = 100mA, I _B = 0	45 60 80			V V V
BV _{CBO}	Breakdown Voltage :	BD375 BD377 BD379	$I_C = 100\mu A, I_E = 0$	50 75 100		45 1	V V V
I _{CBO}	:	BD375 BD377 BD379	$V_{CB} = 45V, I_{E} = 0$ $V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$	E	WW	2 2 2	μΑ μΑ μΑ
I _{EBO}	Emitter Cut-off Current		$V_{EB} = 5V, I_{C} = 0$			100	μΑ
h _{FE1} h _{FE2}	* DC Current Gain	2 400	$V_{CE} = 2V, I_{C} = 0.15A$ $V_{CE} = 2V, I_{C} = 1A$	40 20		375	
V _{CE} (sat)	* Collector-Emitter Saturation \	Voltage	$I_C = 1A, I_B = 0.1A$			1	V
V _{BE} (on)	* Base-Emitter ON Voltage		$V_{CE} = 2V, I_{C} = 1A$			1.5	V
t _{ON}	Turn ON Time		$V_{CC} = 30V, I_{C} = 0.5A$		50		ns
t _{OFF}	Turn OFF Time		$I_{B1} = -I_{B2} = 0.05A$ $R_L = 60\Omega$		500		ns

^{*} Pulse Test: PW=350µs, duty Cycle=2% Pulsed

h_{FE} Classification

	! -						
	Classification	6	10	16	25		
PDF	h _{FE1}	40 ~ 100	63 ~ 160	100 ~ 250	150 ~ 375		

Typical Characteristics

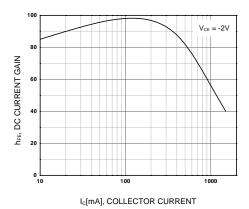


Figure 1. DC current Gain

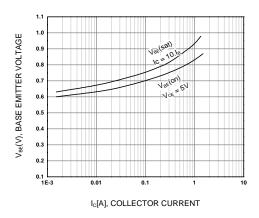


Figure 3. Base-Emitter Voltage

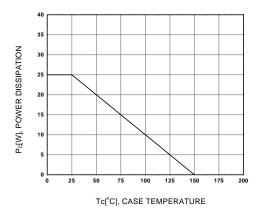


Figure 5. Power Derating

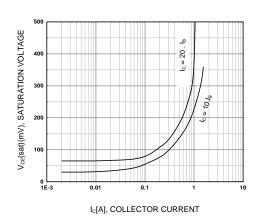


Figure 2. Collector-Emitter Saturation Voltage

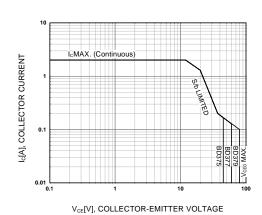
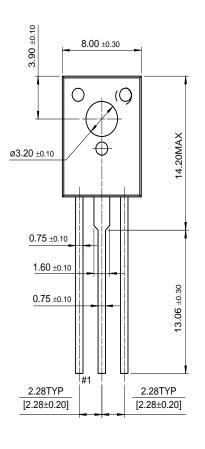


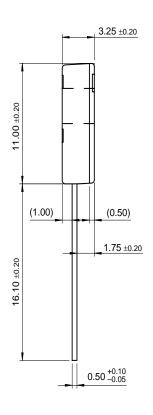
Figure 4. Safe Operating Area

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Package Demensions

TO-126







Dimensions in Millimeters

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